NSN 5961-01-471-1819

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Inclosure Material:

Ceramic

Overall Length:

Between 0.690 inches and 0.770 inches

Overall Height:

0.175 inches

Overall Width:

0.325 inches

End Application:

Aircraft f-14

Internal Configuration:

Field effect

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage

Power Rating Per Characteristic:

1.4 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

14 pin

Specification Data:

81349-mil-prf-19500/599c government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.